Panasonic

2SD0601A (2SD601A)

Silicon NPN epitaxial planar type

For general amplification

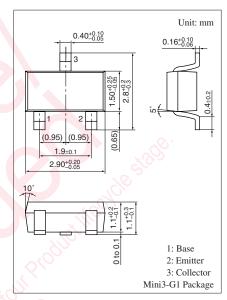
Complementary to 2SB0709A (2SB709A)

Features

- \bullet High foward current transfer ratio h_{FE}
- \bullet Low collector to emitter saturation voltage $V_{\mbox{CE(sat)}}$
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

Absolute Maximum Ratings $T_a = 25^{\circ}C$

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Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	60	V
Collector-emitter voltage (Base open)	V _{CEO}	50	V
Emitter-base voltage (Collector open)	V _{EBO}	7	V
Collector current	I _C	100	mA
Peak collector current	I _{CP}	200	mA
Collector power dissipation	P _C	200	mW
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C
			XVI



Marking Symbol: Z

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 10 \ \mu A, I_{\rm E} = 0$	60	10° . (C	0	V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$	50	00		V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	7	82		V
Collector-base cut-off current (Emitter open)	I _{CBO}	$V_{CB} = 20 \text{ V}, I_E = 0$	0		0.1	μΑ
	I _{CEO}	$V_{CE} = 10 V, I_B = 0$			100	μΑ
Forward current transfer ratio	h _{FE1} *	$V_{CE} = 10 \text{ V}, I_C = 2 \text{ mA}$	160		460	
	h _{FE2}	$V_{CE} = 2 V, I_C = 100 mA$	90			
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 100 \text{ mA}, I_{\rm B} = 10 \text{ mA}$		0.1	0.3	V
Transition frequency	f _T	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz
Noise voltage	NV	$V_{CE} = 10 \text{ V}, I_C = 1 \text{ mA}, G_V = 80 \text{ dB}$		110		mV
		$R_g = 100 \text{ k}\Omega$, Function = FLAT				
Collector output capacitance	C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$			3.5	pF
(Common base, input open circuited)						

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

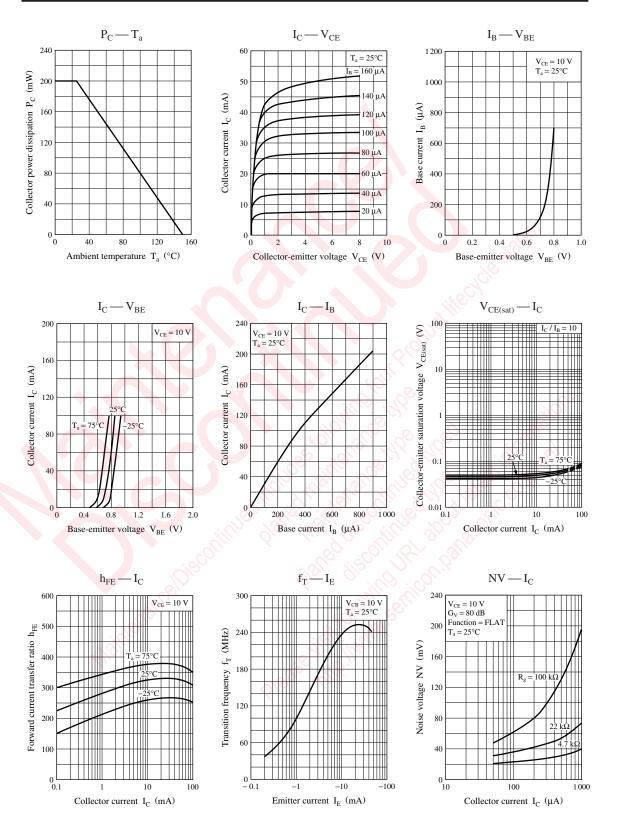
2. *: Rank classification

Rank	Q	R	S	No-rank
h _{FE1}	160 to 260	210 to 340	290 to 460	160 to 460
Marking symbol	ZQ	ZR	ZS	Z

Product of no-rank is not classified and have no marking symbol for rank.

Note) The part number in the parenthesis shows conventional part number.

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